S71GL-N Based MCPs

Stacked Multi-Chip Product (MCP)
Flash Memory and RAM
64/32 Megabit (4/2 M x 16-bit) CMOS 3.0 Volt-only
Page Mode Flash Memory and
32/16/8/4 Megabit (2M/1M/512k/256k x 16-bit) Pseudo Static RAM



Data Sheet (Advance Information)

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When a product has been in production for a period of time such that no changes or only nominal changes are expected, the Preliminary designation is removed from the data sheet. Nominal changes may include those affecting the number of ordering part numbers available, such as the addition or deletion of a speed option, temperature range, package type, or V_{IO} range. Changes may also include those needed to clarify a description or to correct a typographical error or incorrect specification. Spansion Inc. applies the following conditions to documents in this category:

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Data Sheet (Advance Information)

Distinctive Characteristics

MCP Features

- Power supply voltage of 2.7 to 3.1 volt
- High performance
 - 90 ns access time (90 ns Flash, 70 ns pSRAM/SRAM)
 - 25 ns page read times

■ Packages

- 7 x 9 x 1.2 mm 56 ball FBGA
- Operating Temperature
 - -25°C to +85°C

General Description

The S71GL-N product series consists of S29GL-N Flash memory with pSRAM combinations defined as:

| | | Flash Memory Density | |
|---------------|-------|----------------------|-------------|
| | | 32 Mb | 64 Mb |
| pSRAM Density | 4 Mb | S71GL032N40 | |
| | 8 Mb | S71GL032N80 | |
| | 16 Mb | S71GL032NA0 | S71GL064NA0 |
| | 32 Mb | | S71GL064NB0 |

For detailed specifications, please refer to the individual data sheets.

| Document | Publication Identification Number (PID) | |
|----------------------------|---|--|
| S29GL-N | S29GL-N_00 | |
| 4 Mb pSRAM Type 9 | pSRAM_33 | |
| 8 Mb pSRAM Type 9 | pSRAM_34 | |
| 16 Mb pSRAM Type 10 | pSRAM_45 | |
| 16 Mb pSRAM Type 7 | pSRAM_13 | |
| 32 Mb pSRAM Type 8, 130 nm | pSRAM_31 | |
| 32 Mb pSRAM Type 8, 90 nm | Compspec_02 | |



1. Product Selector Guide

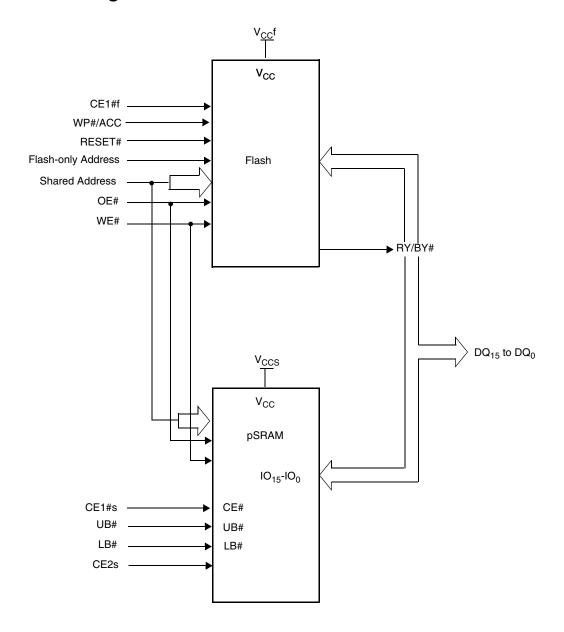
| Device-Model# (Note) | Flash Access time (ns) | (p)SRAM density | (p)SRAM Access time (ns) | (p)SRAM type | Package |
|----------------------|------------------------|--------------------|-----------------------------|--------------|---------|
| S71GL032N40-0K | | 4 Mb | | | |
| S71GL032N40-0P | | 4 IVID | | ~CDAM O | |
| S71GL032N80-0K | | 0.141 | | pSRAM 9 | |
| S71GL032N80-0P | | 8 Mb | | | TI 00-0 |
| S71GL032NA0-0B | | | | pSRAM 10 | TLC056 |
| S71GL032NA0-0F | 90 | | | pSRAM 10 | |
| S71GL032NA0-0U | | | 70 | - OD AM7 | |
| S71GL032NA0-0Z | | 40 Mb | 70 | pSRAM7 | |
| S71GL064NA0-0B | | 16 Mb | | pSRAM 10 | |
| S71GL064NA0-0F | | | | pSRAM 10 | |
| S71GL064NA0-0U | | | | - OD AM7 | T00050 |
| S71GL064NA0-0Z | | | | pSRAM7 | TSC056 |
| S71GL064NB0-0U | | OO MIL | | pSRAM 8, | |
| S71GL064NB0-0Z | | 32 Mb | | 90 nm/130 nm | |

Note

Please see the valid combinations table for the model# description.



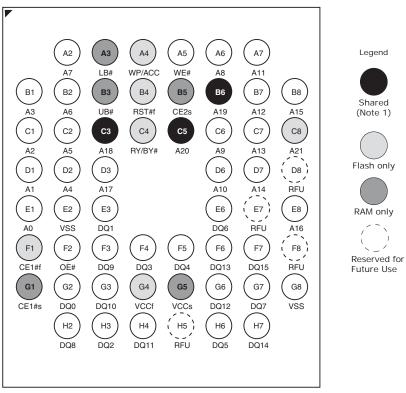
2. MCP Block Diagram





3. Connection Diagram

56-ball Fine-Pitch Ball Grid Array (Top View, Balls Facing Down)



NoteMay be shared depending on density.

| MCP | Flash-only Addresses | Shared Addresses |
|-------------|----------------------|------------------|
| S71GL032NA0 | A20 | A19-A0 |
| S71GL032N80 | A20-A19 | A18-A0 |
| S71GL032N40 | A20-A18 | A17-A0 |
| S71GL064NB0 | A21 | A20-A0 |
| S71GL064NA0 | A21-A20 | A19-A0 |

3.1 Special Handling Instructions For FBGA Package

Special handling is required for Flash Memory products in FBGA packages.

Flash memory devices in FBGA packages may be damaged if exposed to ultrasonic cleaning methods. The package and/or data integrity may be compromised if the package body is exposed to temperatures above 150°C for prolonged periods of time.



4. Pin Description

| Pin | Description |
|-------------------|---|
| A21-A0 | 22 Address Inputs (Common and Flash only) (A20-A0 for the S71GL032N) |
| DQ15-DQ0 | 16 Data Inputs/Outputs (Common) |
| CE1#f | Chip Enable (Flash) |
| CE1#s | Chip Enable 1 (pSRAM/SRAM) |
| CE2s | Chip Enable 2 (pSRAM/SRAM) |
| OE# | Output Enable (Common) |
| WE# | Write Enable (Common) |
| RY/BY# | Ready/Busy Output (Flash 1) |
| UB# | Upper Byte Control (pSRAM/SRAM) |
| LB# | Lower Byte Control (pSRAM/SRAM) |
| RESET# | Hardware Reset Pin, Active Low (Flash) |
| WP#/ACC | Hardware Write Protect/Acceleration Pin (Flash) |
| V _{CC} f | Flash 3.0 volt-only single power supply (see <i>Product Selector Guide</i> for speed options and voltage supply tolerances) |
| V _{CCS} | pSRAM/SRAM Power Supply |
| V _{SS} | Device Ground (Common) |
| NC | Pin Not Connected Internally |



5. Ordering Information

The order number is formed by a valid combinations of the following:

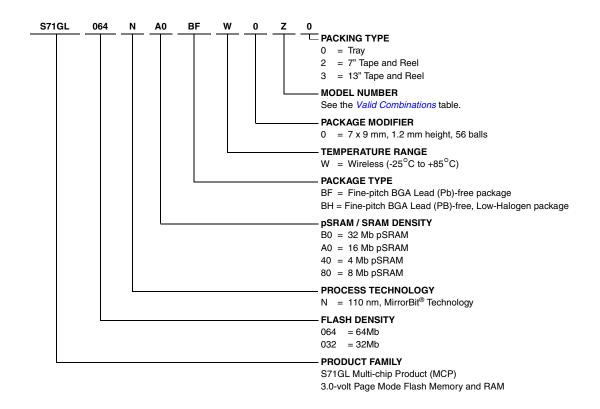


Table 5.1 Valid Combinations

| S71GL064N Valid Combinations | | | Speed Options (ns)/Boot | (p)SRAM Type/ | Dookono | |
|------------------------------|--------------------------|----------------------------------|-------------------------|-------------------------|---------------------|--------------------|
| Base Ordering Part Number | Package & Temperature | Package Modifier/Model Number | Packing Type | Sector Option | Access Time (ns) | Package Marking |
| S71GL032N40 | | 0K | | 90 / Bottom Boot Sector | pSRAM9 / 70 | |
| 37 IGE032N40 | BFW, BHW | 0P | | 90 / Top Boot Sector | p5RAM9 / 70 | TLC056 |
| S71GL032N80 | DEVV, DEVV | 0K | | 90 / Bottom Boot Sector | pSRAM9 / 70 | |
| 37 IGL032N60 | | 0P | | 90 / Top Boot Sector | | |
| C71 CL 020NA0 | 27.01.000110 | 0B | | 90 / Bottom Boot Sector | pSRAM10 / 70 | |
| S71GL032NA0 BHW | БПVV | 0F | | 90 / Top Boot Sector | | |
| S71GL032NA0 BFW, BHW | 0U | 0, 2, 3 (1) | 90 / Bottom Boot Sector | pSRAM7 / 70 | | |
| | 0Z | | 90 / Top Boot Sector | | | |
| 071010040100 | DUM | 0B | | 90 / Bottom Boot Sector | ~CDAM10 / 70 | |
| S71GL064NA0 BHW | 0F | l | 90 / Top Boot Sector | pSRAM10 / 70 | | |
| S71GL064NA0 | DEW DUW | 0U | | 90 / Bottom Boot Sector | - ODAMZ / ZO | TCC0F/ |
| S71GL064NA0 | | 0Z | | 90 / Top Boot Sector | pSRAM7 / 70 | TSC056 |
| S71GL064NB0 | BFW, BHW | 0U | | 90 / Bottom Boot Sector | ~CDAM0 / 70 | |
| S71GL064NB0 | | 0Z | | 90 / Top Boot Sector | - pSRAM8 / 70 | |

Note

Valid Combinations

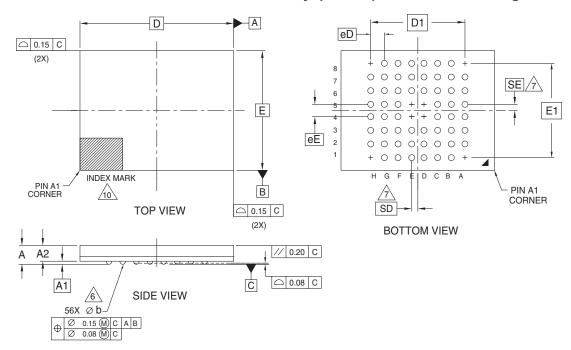
Valid Combinations list configurations planned to be supported in volume for this device. Consult your local sales office to confirm availability of specific valid combinations and to check on newly released combinations.

^{1.} Type 0 is standard. Specify other options as required.



6. Physical Dimensions

6.1 TLC056—56-ball Fine-Pitch Ball Grid Array (FBGA) 9 x 7 mm Package



| PACKAGE | TLC 056 | | | |
|---------|------------------------------|-----|---------|--------------------------|
| JEDEC | N/A | | | |
| DxE | 9.00 mm x 7.00 mm PACKAGE | | mm | |
| SYMBOL | MIN | NOM | MAX | NOTE |
| Α | | | 1.20 | PROFILE |
| A1 | 0.20 | | | BALL HEIGHT |
| A2 | 0.81 | | 0.97 | BODY THICKNESS |
| D | 9.00 BSC. | | | BODY SIZE |
| Е | 7.00 BSC. | | | BODY SIZE |
| D1 | 5.60 BSC. | | | MATRIX FOOTPRINT |
| E1 | 5.60 BSC. | | | MATRIX FOOTPRINT |
| MD | 8 | | | MATRIX SIZE D DIRECTION |
| ME | 8 | | | MATRIX SIZE E DIRECTION |
| n | 56 | | | BALL COUNT |
| φb | 0.35 0.40 0.45 | | 0.45 | BALL DIAMETER |
| eЕ | 0.80 BSC. | | | BALL PITCH |
| eD | 0.80 BSC | | | BALL PITCH |
| SD / SE | 0.40 BSC. | | | SOLDER BALL PLACEMENT |
| | A1,A8,D4,D5,E4,E5,H1,H8 | | 5,H1,H8 | DEPOPULATED SOLDER BALLS |

NOTES:

- DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- 3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010.
- 4. Θ REPRESENTS THE SOLDER BALL GRID PITCH.
- SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION.

SYMBOL "ME" IS THE BALL MATRIX SIZE IN THE "E" DIRECTION.

n IS THE NUMBER OF POPULTED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.

Ó DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.

SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW.

WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW SD OR SE = 0.000.

WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = $\boxed{6/2}$

8. "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.

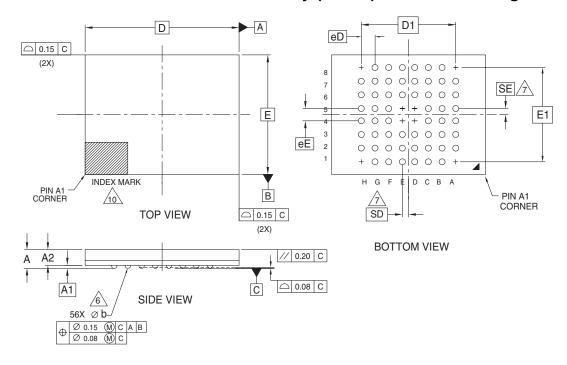
9. N/A

1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.

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6.2 TSC056—56-ball Fine-Pitch Ball Grid Array (FBGA) 9 x 7 mm Package



| PACKAGE | TSC 056 | | | |
|---------|------------------------------|-----|---------|--------------------------|
| JEDEC | N/A | | | |
| DxE | 9.00 mm x 7.00 mm PACKAGE | | mm | |
| SYMBOL | MIN | NOM | MAX | NOTE |
| Α | | | 1.20 | PROFILE |
| A1 | 0.17 | | | BALL HEIGHT |
| A2 | 0.81 | | 0.97 | BODY THICKNESS |
| D | 9.00 BSC. | | | BODY SIZE |
| Е | 7.00 BSC. | | | BODY SIZE |
| D1 | 5.60 BSC. | | | MATRIX FOOTPRINT |
| E1 | 5.60 BSC. | | | MATRIX FOOTPRINT |
| MD | 8 | | | MATRIX SIZE D DIRECTION |
| ME | 8 | | | MATRIX SIZE E DIRECTION |
| n | 56 | | | BALL COUNT |
| φb | 0.35 0.40 0.45 | | 0.45 | BALL DIAMETER |
| eЕ | 0.80 BSC. | | | BALL PITCH |
| eD | 0.80 BSC | | | BALL PITCH |
| SD / SE | 0.40 BSC. | | | SOLDER BALL PLACEMENT |
| | A1,A8,D4,D5,E4,E5,H1,H8 | | i,H1,H8 | DEPOPULATED SOLDER BALLS |

NOTES:

- I. DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- 3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010.
- 4. e REPRESENTS THE SOLDER BALL GRID PITCH.
- 5. SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION.

SYMBOL "ME" IS THE BALL MATRIX SIZE IN THE "E" DIRECTION.

n is the number of populted solder ball positions for matrix size MD x Me.

DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.

WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW SD OR SE = 0.000.

WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = $\boxed{e/2}$

8. "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.

Q Ν/Δ

10 A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.

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7. Revision History

| Section | Description | | | | |
|--------------------------------|--|--|--|--|--|
| Revision 01 (May 14, 2007) | | | | | |
| | Initial release. | | | | |
| Revision 02 (June 19, 2007) | | | | | |
| Global | Editorial changes to valid combinations table | | | | |
| Revision 03 (March 25, 2008) | | | | | |
| Ordering Information | Added Low-Halogen option to package type. | | | | |
| Revision 04 (October 31, 2008) | | | | | |
| General Description | Added pSRAM Type 8, 90 nm | | | | |
| Product Selector Guide | Added pSRAM Type 8, 90 nm | | | | |
| Product Selector Guide | Changed S71GL064Nxx-xx package to TSC056 | | | | |
| Ordering Information | Changed S71GL064Nxx-xx package to TSC056 | | | | |
| Physical Dimensions | Added TSC056 | | | | |
| Revision 05 (January 20, 2009) | , | | | | |
| Global | Added OPNs S71GL032NA0BHW0B/0F and S71GL064NA0BHW0B/0F | | | | |
| General Description | Added pSRAM Type 10 | | | | |



Colophon

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